

MBR1030CT - MBR1060CT

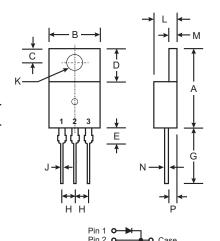
10A SCHOTTKY BARRIER RECTIFIER

Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- Lead Free Finish, RoHS Compliant (Note 3)

Mechanical Data

- Case: TO-220AB
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Polarity: As Marked on Body
- Terminals: Finish Bright Tin. Solderable per MIL-STD-202, Method 208
- Marking: Type Number
- Weight: 2.24 grams (approx.)



TO-220AB					
Dim	Min	Max			
Α	14.48	15.75			
В	10.00	10.40			
С	2.54	3.43			
D	5.90	6.40			
E	2.80	3.93			
G	12.70	14.27			
Н	2.40	2.70			
J	0.69	0.93			
K	3.54	3.78			
L	4.07	4.82			
M	1.15	1.39			
N	0.30	0.50			
Р	2.04	2.79			
All Dimensions in mm					

Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

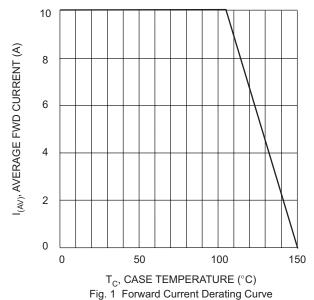
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	MBR 1030CT	MBR 1035CT	MBR 1040CT	MBR 1045CT	MBR 1050CT	MBR 1060CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		30	35	40	45	50	60	٧
RMS Reverse Voltage	V _{R(RMS)}	21	24.5	28	31.5	35	42	V
Average Rectified Output Current (Note 1) @ T _C = 105°C		10					Α	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)		125					А	
Repetitive Peak Reverse Surge Current @ $t \le 2.0 \mu s$		1.0					Α	
Forward Voltage Drop		0.57 0.70 0.70 0.80 0.84 0.95				80	٧	
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$		0.1 15					mA	
Typical Junction Capacitance (Note 2)		150					pF	
Typical Thermal Resistance Junction to Case (Note 1)		30					K/W	
Voltage Rate of Change (Rated V _R)		1000						V/μs
Operating and Storage Temperature Range		-65 to +150						°C

Notes:

- 1. Thermal resistance junction to case mounted on heatsink.
- 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 3. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see EU Directive Annex Notes 5 and 7.





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MBR1050CT / MBR1060CT

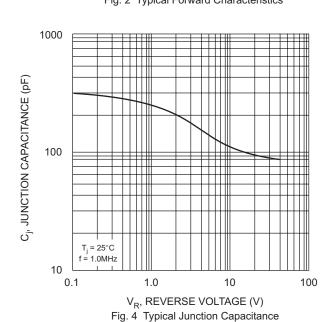
T_j = 25°C

Pulse Width = 300µs
2% Duty Cycle

V_F, INSTANTANEOUS FORWARD VOLTAGE (V)

Fig. 2 Typical Forward Characteristics

300 (V) 250 250 200 150 100 100 NUMBER OF CYCLES AT 60Hz



Ordering Information (Note 4)

Device	Packaging	Shipping
MBR10xxCT*	TO-220AB	50/Tube

^{*} xx = Device type, e.g. MBR1045CT

Notes: 4. For packaging details, visit our website at http://www.diodes.com/datasheets/ap02008.pdf.

Fig. 3 Max Non-Repetitive Surge Current